# Preparation of RuSr<sub>2</sub>GdCu<sub>2</sub>O<sub>8</sub> Compounds with Enhanced Superconducting Transition Temperature

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The RuSr<sub>2</sub>GdCu<sub>2</sub>O<sub>8</sub> (Ru1212) crystal with the highest superconducting transition temperature  $T_{c(end)}$ =54.0 K ( $T_{c(onset)}$ =65.0 K) has been obtained from the nominal composition of Ru:Sr:Gd:Cu=0.9:2.0:1.0:2.1. The prepared compounds are not in a single Ru1212 phase and contain a small amount of Sr<sub>2</sub>GdRuO<sub>6</sub> and SrRuO<sub>3</sub> impurity phases. Possible correlation between the high- $T_c$  phase and the impurity phase is discussed.

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### 1. INTRODUCTION

The coexistence of superconductivity and ferromagnetism in the RuSr<sub>2</sub> GdCu<sub>2</sub>O<sub>8</sub> (Ru1212) compound has raised considerable interest<sup>1,2</sup>. The crystal structure of Ru1212 is an analog of YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> with complete replacement of the Cu-O chains by RuO<sub>6</sub> octahedra. There are many researches of this system, e.g., electrical, magnetic, structural and thermal properties, aiming to elucidate the interplay between superconductivity and magnetism in high- $T_c$  oxides<sup>3-5</sup>. The reported superconducting transition temperature  $T_c$  is, however, fairly dispersed  $(T_{c(end)}(\text{zero resistance } T_c)=15\sim45 \text{ K}^{2,4-6})$ and the systematic relation between  $T_c$  and the oxygen and ruthenium contents has not been well established. Recently, Klamut et al. investigated the superconductivity in the Ru-deficient Ru<sub>1-X</sub>Sr<sub>2</sub>GdCu<sub>2+X</sub>O<sub>8-n</sub> compounds sintered under a high oxygen pressure<sup>7</sup> and the onset  $T_c$  is significantly enhanced up to  $T_{c(onset)}$ =72 K for the X=0.3 and 0.4 samples. We fabricated the RuSr<sub>2</sub>GdCu<sub>2</sub>O<sub>8</sub> and Ru<sub>1-X</sub>Sr<sub>2</sub>GdCu<sub>2+X</sub>O<sub>8</sub> compounds under atmospheric pressure using various sintering and annealing temperatures. Under proper conditions, the Ru1212 system was found to achieve zero resistance at as high as 54.0 K.

#### 2. EXPERIMENTAL

RuSr<sub>2</sub>GdCu<sub>2</sub>O<sub>8</sub> samples were prepared from stoichiometric mixtures of RuO<sub>2</sub>, SrCO<sub>3</sub>, Gd<sub>2</sub>O<sub>3</sub> and CuO powders. The mixtures were calcined at 950°C for 30 h in N<sub>2</sub> atmosphere, pressed into pellets and then sintered at various sintering temperatures  $T_s$  (=1120 ~ 1250°C) for 30 h in flowing O<sub>2</sub>. The sintered samples were heat-treated at 1000°C for 168 h in flowing O<sub>2</sub>. The Ru deficient Ru<sub>1-X</sub>Sr<sub>2</sub>GdCu<sub>2+X</sub>O<sub>8</sub> compounds (X=0.1, 0.2 and 0.3) were also fabricated under the same conditions. The electrical resistivity  $\rho(T)$  was measured by a standard four-terminal method and the magnetization M(T) was measured by a SQUID magnetometer. X-ray diffraction (XRD) data were collected using the CuK $\alpha$  radiation. Rietveld analysis<sup>8</sup> was performed to estimate the lattice parameters (a and c) and the volume fraction ratios of the Ru1212 and other impurity phases.

#### 3. RESULTS AND DISCUSSION

Figure 1(a) shows the temperature dependence of the electrical resistivity  $\rho(T)$  of the annealed samples for various  $T_s$ . The optimum sintering temperature in this system has been believed to be  $T_s \sim 1060^{\circ} \text{C}^{2,4}$ . Since our samples fabricated at  $T_s=1060$  °C were porous and showed the high resistivity and the low  $T_c$  values, we increased  $T_s$  up to just below the melting temperature. This procedure resulted in the  $T_{c(end)}$  increase with the maximum at  $T_{c(end)}$ =49.5 K ( $T_s$ =1170~1220°C). With further increase of  $T_s, T_{c(end)}$  decreased. The absolute value of  $\rho(T)$  showed a minimum for  $T_s=1190$ °C. The  $\rho(T)$  curves are metallic for  $T_s=1150\sim 1220$ °C and show no anomaly at the magnetic ordering temperature  $T_M$  (~130 K). Figure 1(b) presents  $T_{c(end)}$  of the as-sintered and  $O_2$  annealed samples as a function of  $T_s$ . The  $T_{c(end)}$  of 49.5 K was obtained only for the  $O_2$  annealed samples  $(T_{c(onset)}=65.0 \text{ K})$ .  $T_{c(end)}$  increased by about 20 K through annealing. Figure 1(c) shows the magnetization M(T) of the  $T_s=1190$ °C sample after the process of zero field cooling (ZFC). The clear Meissner signals are observable for the applied field of up to 50 G. This result is rather surprising because the Meissner signal has been reported to be detectable only below the applied field of a few Gauss<sup>4,7</sup>.  $T_c$  determined from M(T) is  $\sim 40$  K and significantly lower than that determined from  $\rho(T)$ . M(T) clearly exhibits the sign of magnetic ordering at  $T_M=130$  K.

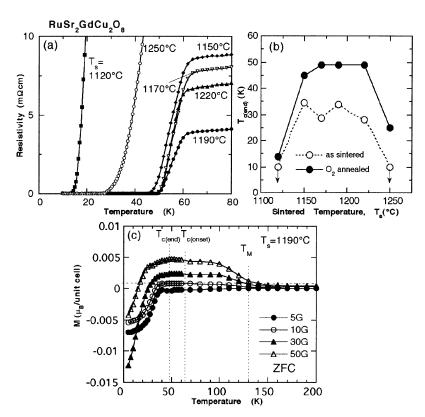


Fig. 1. (a) The temperature dependence of the electrical resistivity  $\rho(T)$  of the  $O_2$  annealed samples for various sintering temperatures  $T_s$ . (b)  $T_{c(end)}$  of the as-sintered and  $O_2$  annealed samples as a function of  $T_s$ . (c) M(T) for the  $T_s$ =1190°C sample after the process of zero field cooling (ZFC).

The prepared compounds, however, turned out not to be in a single Ru1212 phase and contained a small amount of  $Sr_2GdRuO_6$  (211) and  $SrRuO_3$  (113) impurity phases. Figure 2(a) shows the XRD patterns of the samples for various  $T_s$ . The diffraction peaks of the 211 and 113 impurity phases are observable besides those of the Ru1212 phase. The impurity phases seem to somewhat increase with increasing  $T_s$ . For the  $T_s$ =1190°C sample, for example, the volume fractions of the 211 and 113 phases are estimated to be 5.2% and 18.3%, respectively, by the Rietveld analysis, while they are estimated to be 4.7% and 16.3% for  $T_s$ =1150°C. The segregation of these Ru-containing impurity phases suggests the formation of a Ru-poor (and Cu-rich) Ru1212 superconducting phase because the sample prepara-

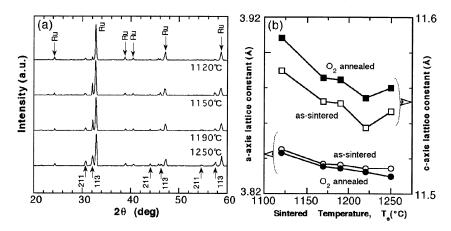


Fig. 2. (a) The XRD patterns of  $RuSr_2GdCu_2O_8$  samples for various  $T_s$ . In this figure, 'Ru', '211' and '113' show the Ru1212,  $Sr_2GdRuO_6$ , and  $SrRuO_3$  phases, respectively. (b) The a- and c-axis lattice parameters of the assintered and  $O_2$  annealed samples as a function of  $T_s$ .

tion started from a stoichiometric mixture of the metallic elements. Figure 2(b) shows the a- and c-axis lattice parameters of the as-sintered and the  $O_2$  annealed samples as a function of  $T_s$ . The a- and c-axis lattice parameters decrease with increasing  $T_s$ . After the annealing in flowing  $O_2$ , the c-axis parameter distinctly increases and the a-axis one slightly decreases. This result implies that the enhancement of  $T_{c(end)}$  by the  $O_2$  anneal is related to the c-axis elongation.

Figure 3(a) shows  $\rho(T)$  of the O<sub>2</sub> annealed Ru<sub>1-X</sub>Sr<sub>2</sub>GdCu<sub>2+X</sub>O<sub>8</sub> samples as a function of X ( $T_s$ =1150°C). For the X=0.1 sample,  $T_{c(end)}$  increases to 54.0 K and then decreases for larger X. The  $\rho$  values in the normal state are also the smallest for X=0.1. Comparing the  $\rho(T)$  curve of the X=0.1 sample ( $T_{c(end)}$ =54.0 K,  $T_{c(onset)}$ =65.0 K) with that of the X=0.4 sample of Klamut et al.<sup>7</sup> with the highest reported  $T_{c(onset)}$  ( $T_{c(end)}$ =46 K,  $T_{c(onset)}$ =72 K), the  $\rho(T)$  transition curve of the present sample does not show the shoulder-like structure characteristic of their high  $T_{c(onset)}$  sample. Figure 3(b) presents the  $T_{c(end)}$  and the resistivity at 100 K,  $\rho(100 \text{ K})$  of the  $T_s$ =1150°C and the  $T_s$ =1180°C samples as a function of X. The  $\rho$  value in the normal state takes a minimum at X=0.1. From the Rietveld analysis of XRD data, it is found that the volume fractions of the impurity phases are reduced for the X=0.1 sample (211: 4.1%, 113: 8.6%), compared with those of the X=0 sample (211: 4.7%, 113: 16.3%). The enhancement of  $T_{c(end)}$  for the Ru<sub>1-X</sub>Sr<sub>2</sub>GdCu<sub>2+X</sub>O<sub>8</sub> (X=0.1) sample may be related to the decrease

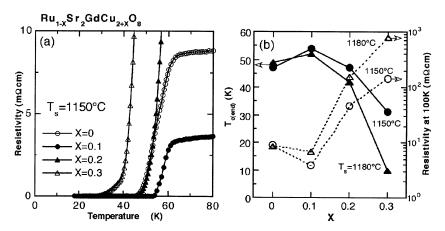


Fig. 3. (a)  $\rho(T)$  of the Ru<sub>1-X</sub>Sr<sub>2</sub>GdCu<sub>2+X</sub>O<sub>8</sub> samples. (b)  $T_{c(end)}$  and the resistivity at 100 K of the respective samples as a function of X.

of the impurity phases.

In summary, the RuSr<sub>2</sub>GdCu<sub>2</sub>O<sub>8</sub> (Ru1212) compounds have been fabricated by the modified sample preparation processes. By setting the nominal composition at Ru:Sr:Gd:Cu=0.9:2.0:1.0:2.1 (X=0.1), the superconducting transition temperature  $T_{c(end)}$ =54.0 K (at zero resistivity) was achieved which is the highest reported so far. The higher  $T_{c(end)}$  may come from the reduction of the contained Sr<sub>2</sub>GdRuO<sub>6</sub> and SrRuO<sub>3</sub> impurity phases, compared with those for the X=0 sample ( $T_{c(end)}$ =49.5 K).

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